

	Type	L #	Hits	Search Text	DBs	Time Stamp
✓ 1	BRS	L1	114	(SOLUTION WITH NICKEL) and TFT\$1	USPAT	2000/06/16 15:43

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1137	(glass with substrate) and (TFT\$2 or (film near transistor\$1)) and (silicon near nitride) and amorphous and metal	USPAT
✓ 2	BRS	L2	318	1 and crystalliz\$6	USPAT
✓ 3	BRS	L3	311	2 and (heat\$3 or anneal\$3)	USPAT
✓ 4	BRS	L4	131	3 and (glass same nitride)	USPAT
✓ 5	BRS	L5	2	glass and silicon and nitride and crystalliz\$6 and amorphous and (orientation or "111")	USOCR; EPO; JPO; Derwent

	Type	L #	Hits	Search Text	DBs
1	IS&R	L1	0	("6067062.pn.").PN.	USPAT
2	BRS	L2	1	6067062.pn.	USPAT
3	BRS	L3	332	(silicon near nitride) and glass and (TFT or (thin near film)) and (crystalliz\$5 with amorphous) and (nickel or palladium or platinum or copper or silver or gold or indium or tin or phosphorous or arsenic or antimony)	USPAT
4	BRS	L4	91	3 and orientation	USPAT
5	BRS	L5	413	((AMORPHOUS WITH CRYSTALLIZ\$5) AND (NITRIDE NEAR SILICON)) AND (TFT OR (THIN NEAR FILM)) AND GLASS)	USPAT
6	BRS	L6	322	5 not 4	USPAT
7	BRS	L7	194	6 and rate	USPAT
8	BRS	L8	36	7 and (heat\$3 with rate)	USPAT

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	1986	nickel and amorphous and crystalliz\$5 and (TFT or film)	USPAT	2000/06/16 14:18
2	BRS	L2	1331	1 and rate	USPAT	2000/06/16 14:18
✓ 3	BRS	L3	132	1 and (heat\$3 with rate) and (cool\$3 with rate)	USPAT	2000/06/16 14:19
✓ 4	BRS	L4	25	3 and lamp	USPAT	2000/06/16 15:09
✓ 5	BRS	L5	212	amorphous and (metal or nickel) and (lower\$3 with temperature)	USOCR; EPO; JPO; Derwen t	2000/06/16 15:11
✓ 6	BRS	L6	60	5 and silicon	USOCR; EPO; JPO; Derwen t	2000/06/16 15:11
✓ 7	BRS	L7	83	5 and (silicon or si)	USOCR; EPO; JPO; Derwen t	2000/06/16 15:11